PNP/NPN Epitaxial Planar Silicon Transistors



2SA1607/2SC4168

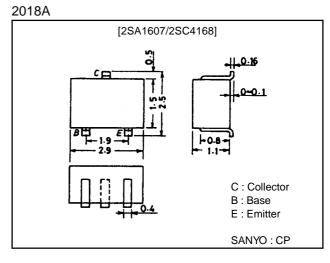
High-Speed Switching Applications

Features

- \cdot Fast switching speed.
- · High gain-bandwidth product.
- · Low saturation voltage.

Package Dimensions

unit:mm



():2SA1607

Specifications

Absolute Maximum Ratings at Ta = 25 C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)40	V
Collector-to-Emitter Voltage	VCEO		(–)20	V
Emitter-to-Base Voltage	V _{EBO}		(–)5	V
Collector Current	ι _C		(–)150	mA
Collector Current (Pulse)	ICP		(–)300	mA
Base Current	Ι _Β		(–)30	mA
Collector Dissipation	PC		200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		–55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)30V, I _E =0			(–)0.1	μA
Emitter Cutoff Current	IEBO	V _{EB} =(-)4V, I _C =0			(–)0.1	μA
DC Current Gain	hFE	V _{CE} =(-)1V, I _C =(-)10mA	60*		270*	
					(180)	
Gain-Bandwidth Product	fT	V _{CE} =(-)10V, I _C =(-)10mA		700		MHz
				(400)		MHz

Continued on next page.

- Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.
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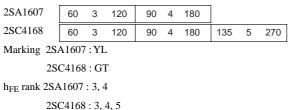
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

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Continued from preceding page.						
Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Output Capacitance	Cob	V _{CB} =(-)10V, f=1MHz		(2.9)		pF
				2.6		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =(-)10mA, I _B =(-)1mA		0.08	(–)0.2	V
				(-0.07)		V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)10mA, I _B =(-)1mA		0.72	(–)1.0	V
				(-0.75)		V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =(-)10μA, I _E =0	(–)40			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(−)1mA, R _{BE} =∞	(–)20			V
Emitter-to-Base Breakdown Votage	V _{(BR)EBO}	I _E =(-)10μΑ, I _C =0	(–)5			V
Delay Time	td	See specified Test Circuit		(14)11	20	ns
Rise Time	tr	See specified Test Circuit		(11)10	20	ns
Storage Time	t _{stg}	See specified Test Circuit		(80)70	180	ns
Fall Time	tf	See specified Test Circuit		(16)15	25	ns

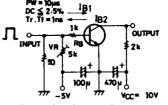
 \ast : The 2SA1607/2SC4168 are classified by 10mA h_{FE} as follows :

-100

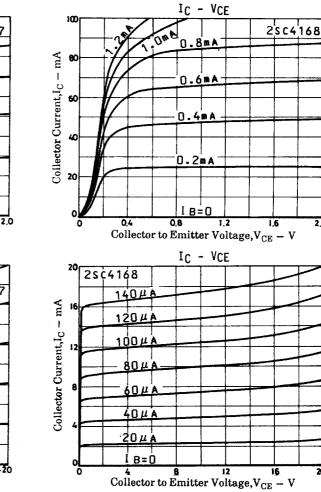


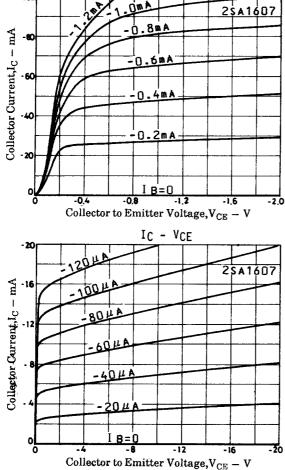
IC - VCE





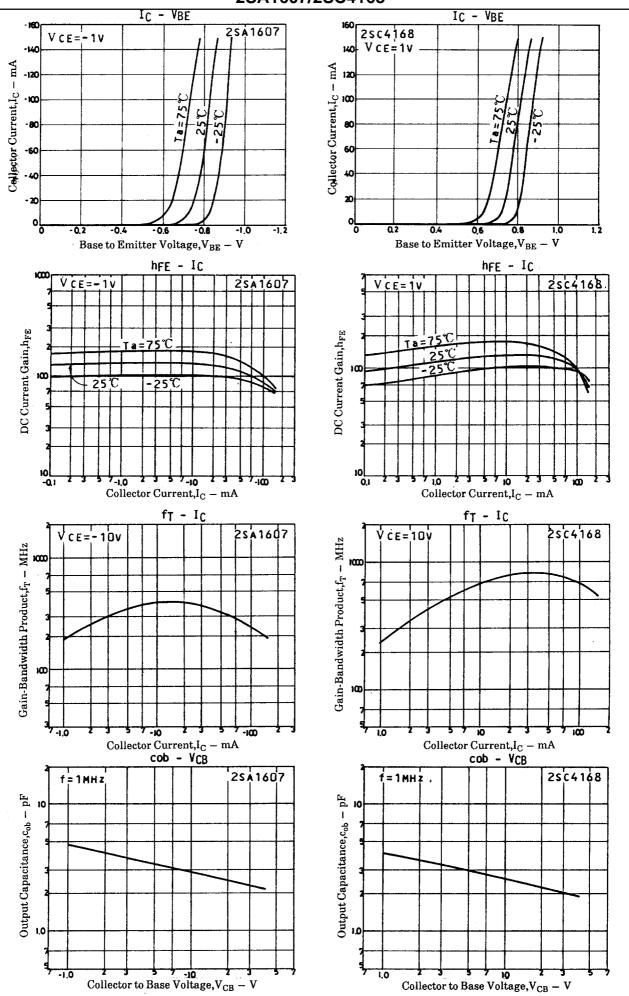
 $5I_{B1}=-5I_{B2}=I_{C}=50$ mA (For PNP, the polarity is reserved.) Unit (reisistance : Ω , capacitance : F)





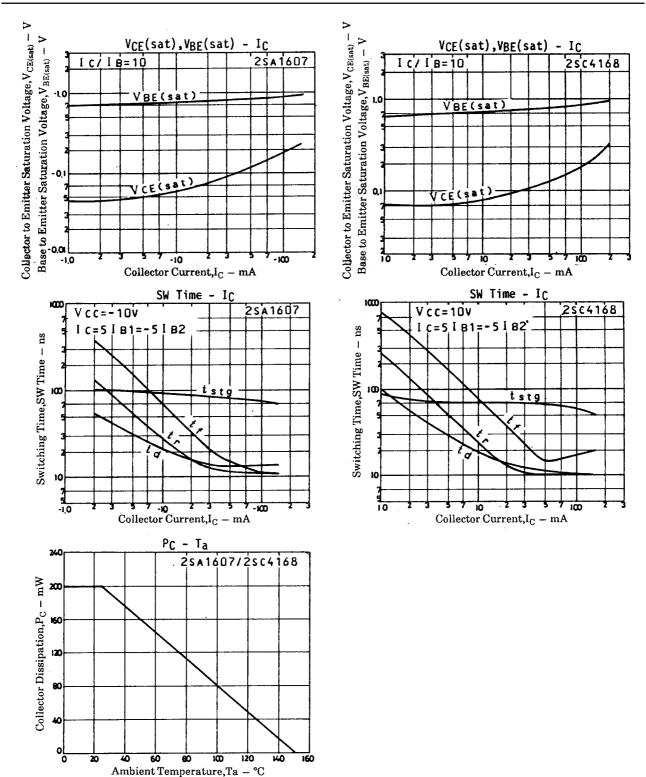
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No.2479-3/5



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